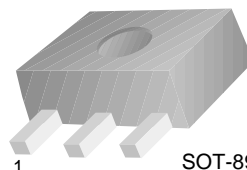


# KSC2982

KSC2982

## Strobe Flash & Medium Power Amplifier

- Excellent  $h_{FE}$  Linearity :  $h_{FE1}=140 \sim 600$
- Low Collector-Emitter Saturation Voltage :  $V_{CE(sat)}=0.5V$
- Collector Dissipation :  $P_C=1\sim 2W$  in Mounted on Ceramic Board



1. Base 2. Collector 3. Emitter

## NPN Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_a=25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	30	V
$V_{CES}$	Collector-Emitter Voltage	30	V
$V_{CEO}$	Collector-Emitter Voltage	10	V
$V_{EBO}$	Emitter Base Voltage	6	V
$I_C$	Collector Current (DC)	2	A
$I_{CP}$	* Collector Current (Pulse)	4	A
$I_B$	Base Current (DC)	0.4	A
$I_{BP}$	* Base Current (Pulse)	0.8	A
$P_C$	Collector Power Dissipation	500	mW
$P_C^*$		1,000	mW
$T_J$	Junction Temperature	150	$^\circ C$
$T_{STG}$	Storage Temperature	-55 ~ 150	$^\circ C$

\*  $PW \leq 10ms$ , Duty Cycles  $\leq 30\%$   
Mounted on Ceramic Board (250mm<sup>2</sup> x 0.8mm)

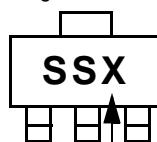
### Electrical Characteristics $T_a=25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C=10mA, I_B=0$	10			V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E=1mA, I_C=0$	6			V
$I_{CBO}$	Collector Cut-off Current	$V_{CB}=30V, I_E=0$			100	nA
$I_{EBO}$	Emitter Cut-off Current	$V_{BE}=6V, I_C=0$			100	nA
$h_{FE1}$ $h_{FE2}$	DC Current Gain	$V_{CE}=1V, I_C=0.5A$ $V_{CE}=1V, I_C=2A$	140 70	140	600	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=2A, I_B=50mA$		0.2	0.5	V
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE}=1V, I_C=2A$		0.86	1.5	V
$f_T$	Current Gain Bandwidth Product	$V_{CE}=1V, I_C=2A$		150		MHz
$C_{ob}$	Output Capacitance	$V_{CB}=10V, I_E=0, f=1MHz$		27		pF

## $h_{FE1}$ Classification

Classification	A	B	C	D
$h_{FE1}$	140 ~ 240	200 ~ 330	300 ~ 450	420 ~ 600

Marking



$h_{FE}$  grade

# Typical Characteristics

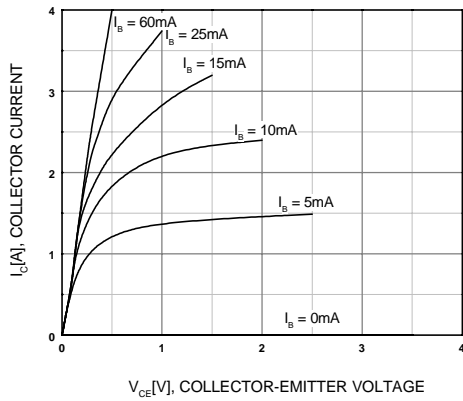


Figure 1. Static Characteristic

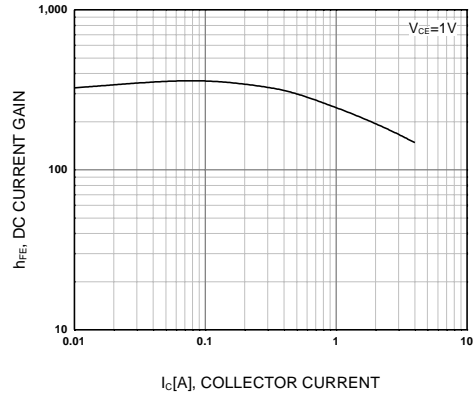


Figure 2. DC current Gain

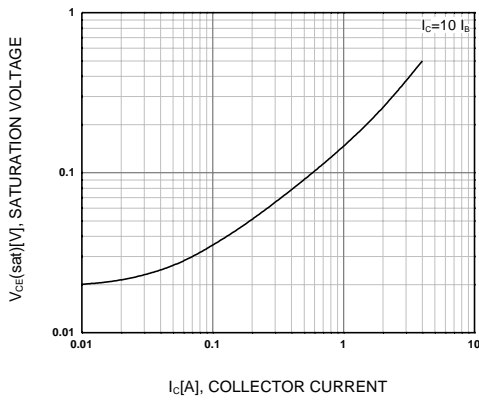


Figure 3. Collector-Emitter Saturation Voltage

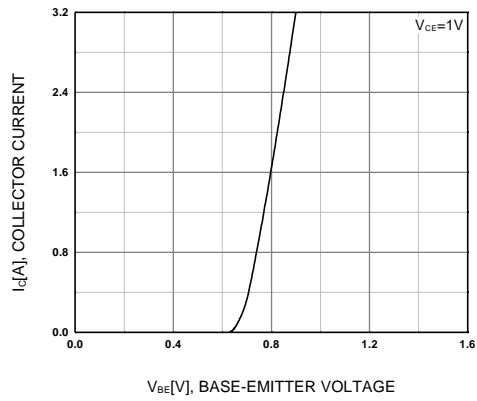


Figure 4. Base-Emitter On Voltage

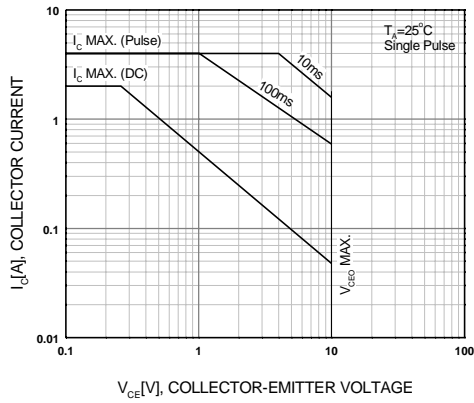


Figure 5. Safe Operating Area

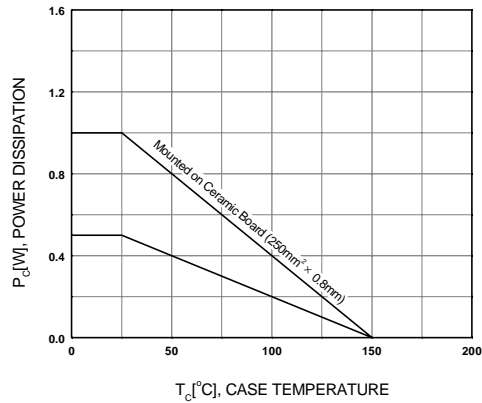
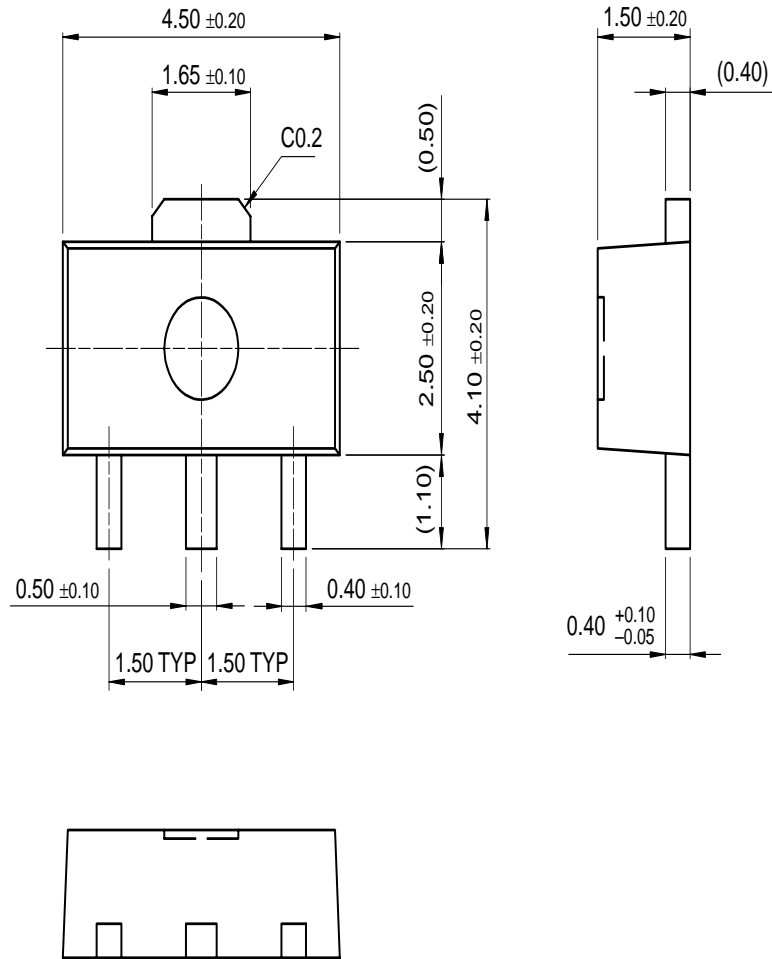


Figure 6. Power Derating

# Package Dimensions

## SOT-89



Dimensions in Millimeters

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ActiveArray <sup>™</sup>	FACT Quiet series <sup>™</sup>	ISOPLANAR <sup>™</sup>	POP <sup>™</sup>	Stealth <sup>™</sup>
Bottomless <sup>™</sup>	FAST <sup>®</sup>	LittleFET <sup>™</sup>	Power247 <sup>™</sup>	SuperSOT <sup>™</sup> -3
CoolFET <sup>™</sup>	FAST <sup>™</sup>	MicroFET <sup>™</sup>	PowerTrench <sup>®</sup>	SuperSOT <sup>™</sup> -6
CROSSVOLT <sup>™</sup>	FRFET <sup>™</sup>	MicroPak <sup>™</sup>	QFET <sup>™</sup>	SuperSOT <sup>™</sup> -8
DOME <sup>™</sup>	GlobalOptoisolator <sup>™</sup>	MICROWIRE <sup>™</sup>	QS <sup>™</sup>	SyncFET <sup>™</sup>
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